

Section I. **(Amendments to the Specification)**

Please replace the paragraph under the heading "Cross-Reference to Related Applications" on the title page of the application, with the following new replacement paragraph:

This is a continuation of U.S. Patent Application No. 08/955,168 filed October 21, 1997, now abandoned, which is a continuation-in-part of U.S. Patent Application No. 08/188,469 filed January 27, 1994, issued October 21, 1997 as U.S. Patent No. 5,679,152 for "Method of Making a Single Crystal Ga*N Article."